

600V MOSFET



Features

- Superjunction Technology
- Low On-Resistance
- **Low Conduction Losses**
- Low Gate Charge
- Integrated Fast Recovery Diode
- High-Speed Switching



Benefits

Optimize system performance and efficiency in diverse applications with typical on-resistance values ranging from $65m\Omega$ to $95m\Omega$, available in a compact TO-247 package.

Integrated fast recovery diode (FRED) options improve recovery times and simplify circuit design, while superjunction technology ensures low conduction losses and minimizes power dissipation for reliable operation in demanding environments.

Applications



applications

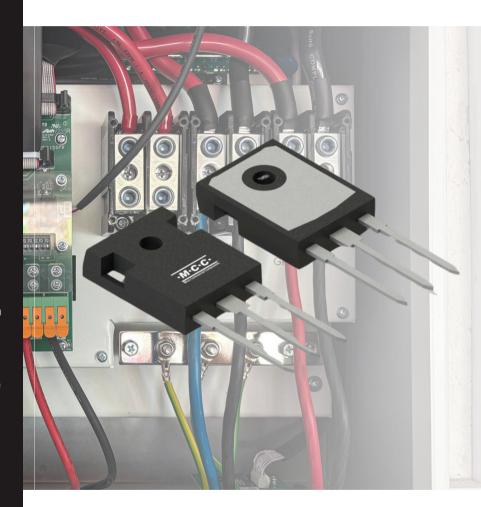






inverters appliancés

MCC's 600V MOSFET: Low RDS(on), **High Performance** & Integrated FRED



Engineered for Low Losses, Fast Switching & **High Efficiency**





600V SJ MOSFETS with integrated **FRED options**



Product Attributes, Parametrics & Datasheets

Product	Туре	Package	Reverse Breakdown- Voltage VRWM	Drain- SourceOn- Resistance (Typ.) RDS(on)	PeakIntegrated Fast Recovery DiodeIPP	MOUNTING	Datasheet
MCW075N60FH	N-Channel Power MOSFET	TO-247	600V	65m Ω	Included	Through- Hole	<u>Info</u>
MCW099N60SH	N-Channel Power MOSFET	TO-247	600V	85mΩ	Not Included	Through- Hole	<u>Info</u>
MCW105N60FH	N-Channel Power MOSFET	TO-247	600V	95m Ω	Included	Through- Hole	<u>Info</u>

Applications:



Power Supplies

- **Battery protection**
- DC-DC converters Robotics
- Power management systems



Motor Drives

- AC-DC converters Industrial motor controls
 - applications



Renewable Energy

- Solar inverters
- Wind power converters



Consumer **Electronics**

- Power adapters and chargers
- High-efficiency appliances



Industrial

- Uninterruptible power supplies (UPS)
- Welding equipment Heating, ventilation, and air conditioning (HVAC) systems

CONTACT MCC TO REQUEST A SAMPLE

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